



SANYO Semiconductors

## DATA SHEET

# CPH3246

 — NPN Epitaxial Planar Silicon Transistor  
**High-Current Switching Applications**

## Applications

- DC / DC converters, relay drivers, lamp drivers, motor drivers, inverters.

## Features

- Adoption of FBET, MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package permitting applied sets to be small and slim (mounting height: 0.9mm).
- High allowable power dissipation.

## Specifications

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		100	V
Collector-to-Emitter Voltage	V <sub>CES</sub>		100	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		60	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		6.5	V
Collector Current	I <sub>C</sub>		3	A
Collector Current (Pulse)	I <sub>CP</sub>		5	A
Base Current	I <sub>B</sub>		600	mA
Collector Dissipation	P <sub>C</sub>	Mounted on a ceramic board (600mm <sup>2</sup> X0.8mm)	0.9	W
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =50V, I <sub>E</sub> =0A			1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	300		600	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA		390		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		15		pF

Marking : DR

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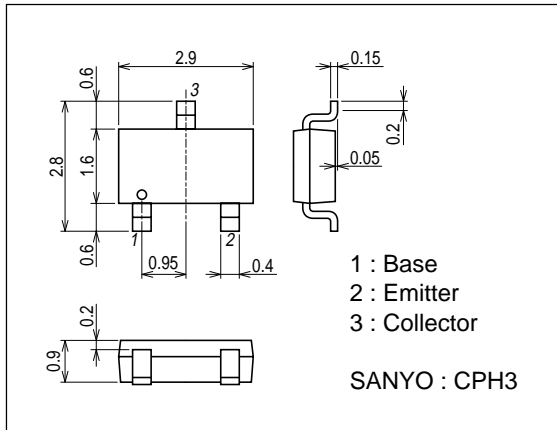
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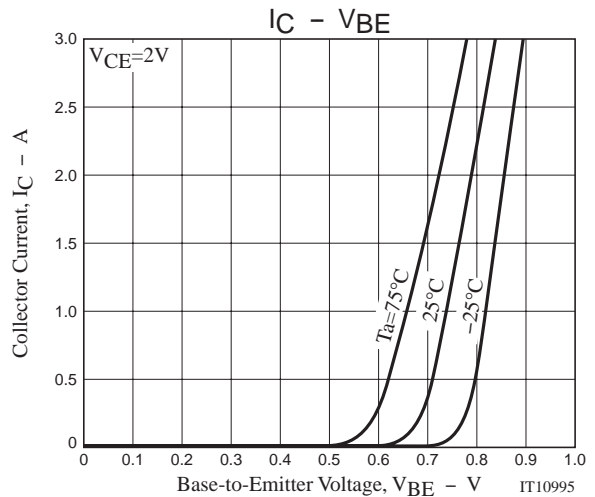
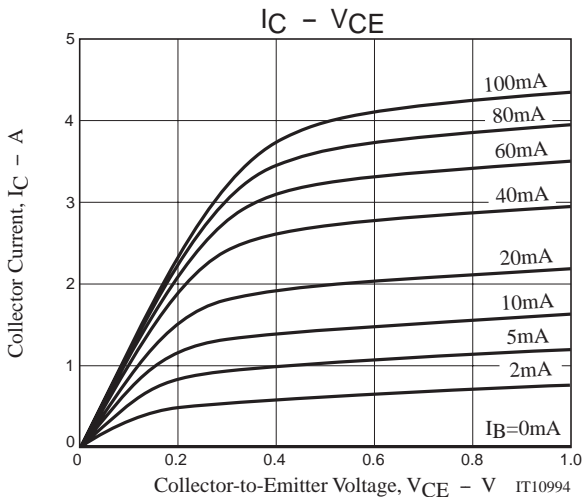
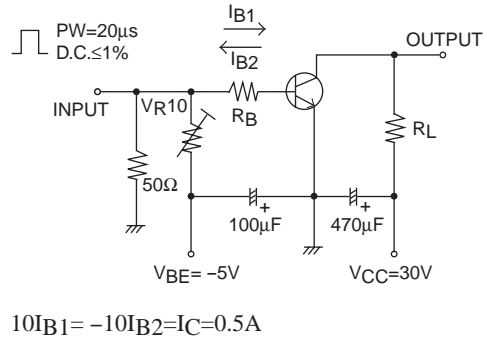
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=1A, I_B=50mA$		80	120	mV
	$V_{CE(sat)2}$	$I_C=1A, I_B=100mA$		70	110	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1A, I_B=100mA$		0.85	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=100\mu A, R_{BE}=0\Omega$	100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	60			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6.5			V
Turn-ON Time	$t_{on}$	See specified Test Circuit.		35		ns
Storage Time	$t_{stg}$	See specified Test Circuit.		680		ns
Fall Time	$t_f$	See specified Test Circuit.		24		ns

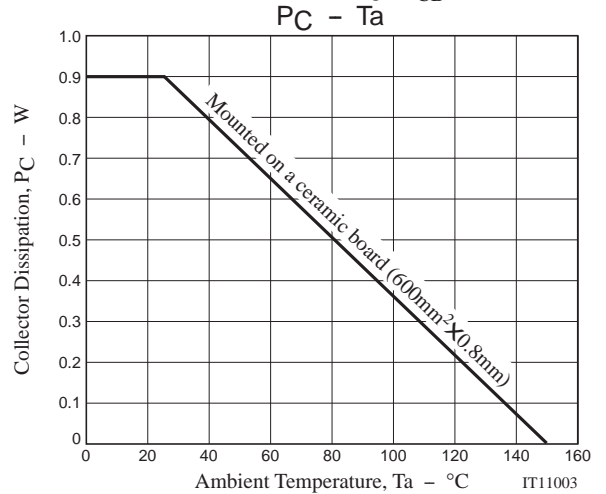
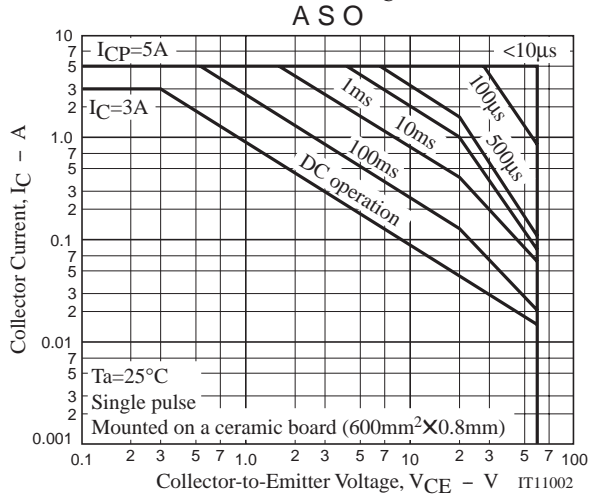
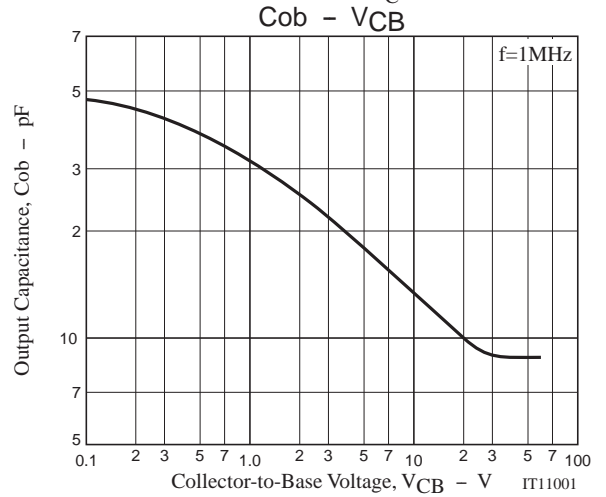
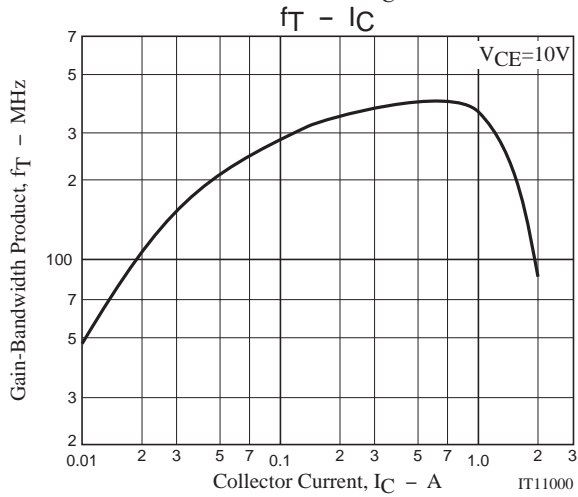
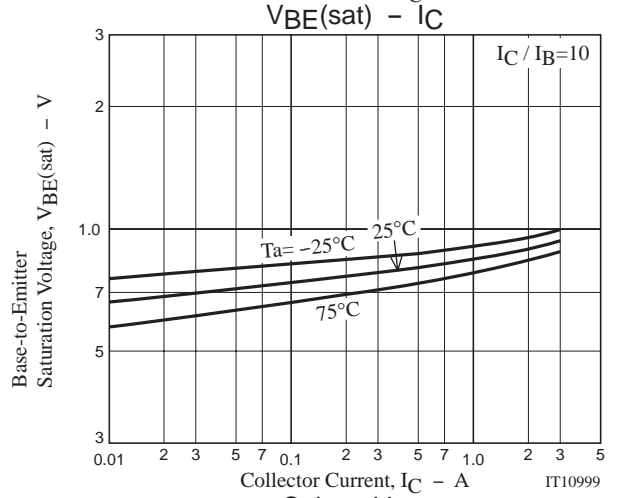
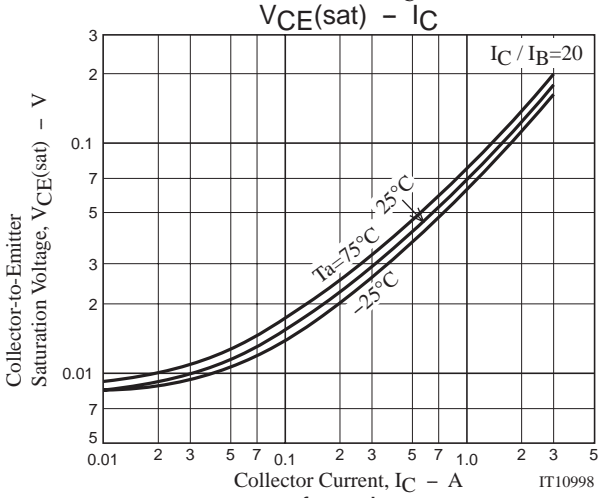
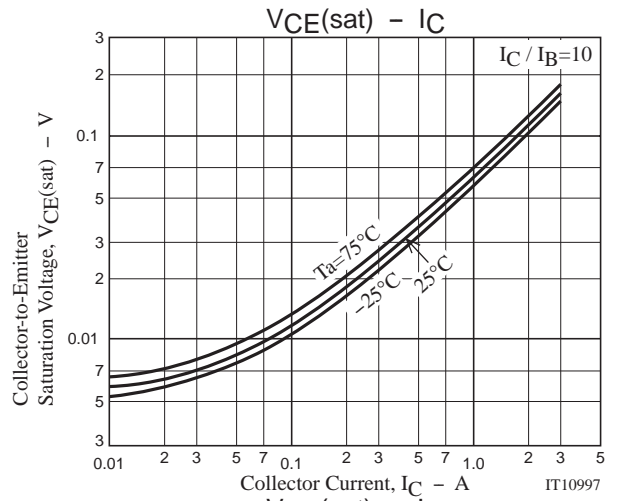
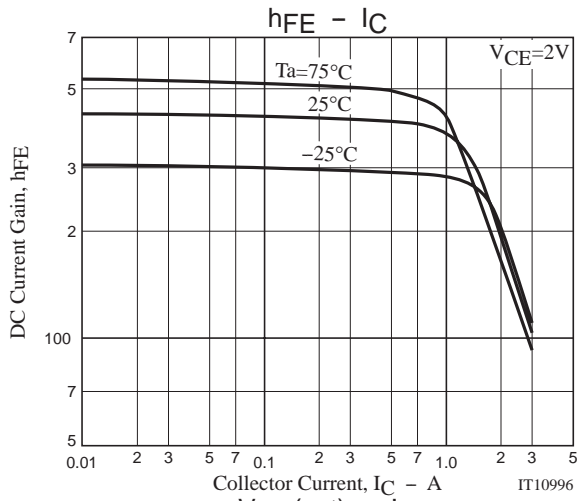
## Package Dimensions

unit : mm  
7015A-003



## Switching Time Test Circuit





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